

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,108,942 B1
APPLICATION NO. : 10/807358
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INVENTOR(S) : Hong Gan and Esther S. Takeuchi

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 3, line 10 reads "IIIB, IIIIB, IVB, VB, VIIB, VIIIB, and VIII"

should be --IIIB, IIIIB, IVB, VB, VIIB, VIIIB and VIII--

Column 3, line 48, reads "Ag₂₀₂"

should be --Ag₂O₂--

Column 5, line 16, reads "where n 1, 2, 3,"

should be --where n = 1, 2, 3,--

Column 6, line 43, reads "fQr"

should be --for--

Column 8, line 17, reads "LiAsF₅"

should be --LiAsF₆--

Column 8, line 18, reads "LiN(SO₂CF₃) 2"

should be --LiN(SO₂CF₃)₂--

Signed and Sealed this

Twelfth Day of December, 2006



JON W. DUDAS
Director of the United States Patent and Trademark Office